



SP03-165

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MAY 02 2005

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Rajaram Bhat, et al
Serial No: 10/718,744
Filed: November 21, 2003
For: GROWTH OF DILUTE NITRIDE
COMPOUNDS

Examiner:
Group Art Unit: 1762

INFORMATION DISCLOSURE STATEMENT
UNDER 37 C.F.R. §§ 1.56, 1.97 – 1.98

Mail Stop Amendment
Commissioner of Patents
Alexandria, VA 22313-1450

Dear Sir:

The Examiner's attention is hereby directed to the following reference(s) listed on the attached Form PTO-1449 for consideration in connection with the examination of the above-identified patent application. One copy of any non-US patent is enclosed.

Each of the enclosed reference(s) was cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this information disclosure statement.

This submission does not represent that a search has been made or that no better art exists and does not constitute an admission that each or all of the enclosed documents constitute "prior art." If it should be determined that any of the submitted documents do not constitute "prior art" under United States law, applicant(s) reserve the right to present to the office the relevant facts and law regarding the appropriate status of such documents.

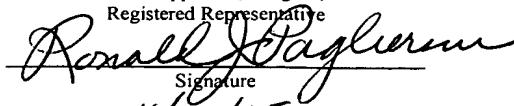
Applicant(s) further reserve the right to take appropriate action to establish the patentability of the disclosed invention over the enclosed references, should one or more of the references be applied against the claims of the present application.

Respectfully submitted,


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I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to Mail Stop Amendment, Commissioner of Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on APRIL 28, 2005
Date of Deposit

Ronald J. Paglierani
Name of applicant, assignee, or
Registered Representative


Signature
4/28/05
Date of Signature



FORM PTO-1449 (MODIFIED)

LIST OF PATENTS AND
PUBLICATIONS
FOR APPLICANTS INFORMATION
DISCLOSURE STATEMENT

ATTORNEY DOCKET NO.

SP03-165

SERIAL NO.

10/718,744

APPLICANT Rajaram Bhat, et al.

FILING DATE November 21,
2003

GROUP: 1762

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

Examiner Initial		Document Number	Date	Name	Class	Sub-Class	Filing Date if Approp.
	AA	5,209,952	5/11/93	Erdmann et al	427	255.6	

FOREIGN PATENT DOCUMENTS

		Document Number	Date	Country	Class	Sub-Class	Translation Yes	No
	AB	WO03/041137	5/15/03	PCT	H01L	21/20	X	
	AB	EP1061083	12/20/00	Europe	C07F	5/00	X	
	AD	EP1361606	11/12/03	Europe	H01L	21/36	X	

OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)

AE	Kurtz, et al.; <i>Incorporation of nitrogen into GaAsN grown by MOCVD using different precursors</i> ; Journal of Crystal Growth 234 (2002) pgs 318-322.
AF	Devi, et al.; <i>A Study of Bisazido (dimethylaminopropyl) gallium as a Precursor for the OMVPE of Gallium Nitride Thin Films in a Cold-Wall Reactor System under Reduced Pressure</i> ; Chemical Vapor Deposition 2000, 6, No. 5, pgs 245-252.

EXAMINER:

DATE CONSIDERED:

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609: draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.